



ST2001FX

HIGH VOLTAGE FAST-SWITCHING NPN POWER TRANSISTOR

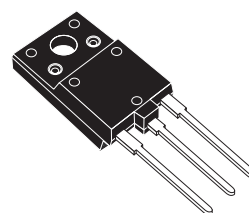
- NEW SERIES, ENHANCED PERFORMANCE
- FULLY INSULATED PACKAGE (U.L. COMPLIANT) FOR EASY MOUNTING
- HIGH VOLTAGE CAPABILITY
- HIGH SWITCHING SPEED
- TIGHTER h_{fe} CONTROL
- IMPROVED RUGGEDNESS

APPLICATIONS:

- HORIZONTAL DEFLECTION FOR COLOR TVS OVER 21 INCHES AND 15 INCHES MONITORS

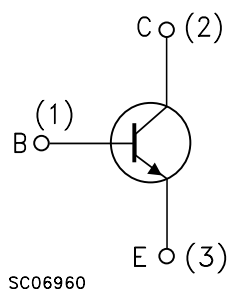
DESCRIPTION

The device is manufactured using Diffused Collector technology for more stable operation Vs base drive circuit variations resulting in very low worst case dissipation.



ISOWATT218FX

INTERNAL SCHEMATIC DIAGRAM



ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter	Value	Unit
V_{CE0}	Collector-Base Voltage ($I_E = 0$)	1500	V
V_{CE0}	Collector-Emitter Voltage ($I_B = 0$)	600	V
V_{EBO}	Emitter-Base Voltage ($I_C = 0$)	7	V
I_C	Collector Current	10	A
I_{CM}	Collector Peak Current ($t_p < 5$ ms)	20	A
I_B	Base Current	7	A
P_{tot}	Total Dissipation at $T_c = 25$ °C	63	W
V_{ins}	Insulation Withstand Voltage (RMS) from All Three Leads to External Heatsink	2500	V
T_{stg}	Storage Temperature	-65 to 150	°C
T_j	Max. Operating Junction Temperature	150	°C

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THERMAL DATA

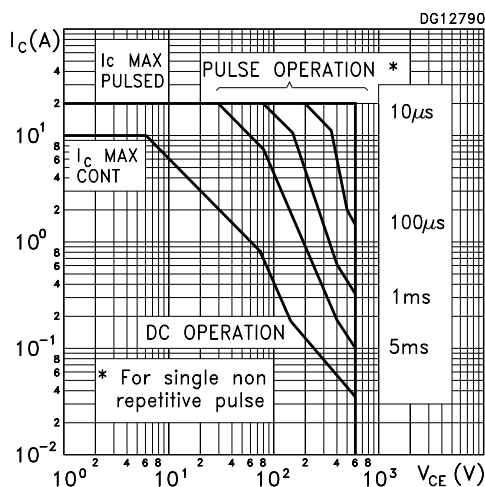
$R_{thj-case}$	Thermal Resistance Junction-case	Max	2	°C/W
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ELECTRICAL CHARACTERISTICS ($T_j = 25\text{ °C}$ unless otherwise specified)

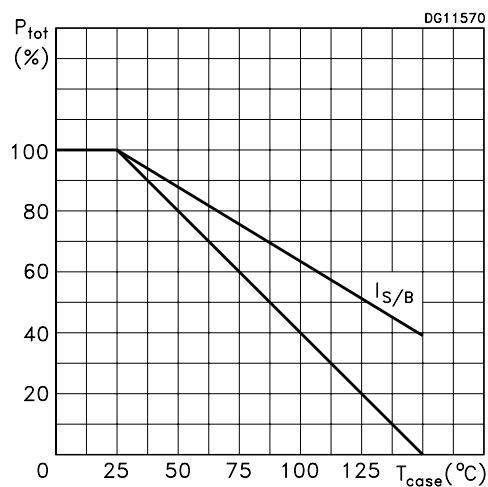
Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Unit
I_{CES}	Collector Cut-off Current ($V_{BE} = 0$)	$V_{CE} = 1500\text{ V}$ $V_{CE} = 1500\text{ V}$ $T_j = 125\text{ °C}$			1 2	mA mA
I_{EBO}	Emitter Cut-off Current ($I_C = 0$)	$V_{EB} = 7\text{ V}$			1	mA
$V_{CEO(sus)}^*$	Collector-Emitter Sustaining Voltage ($I_B = 0$)	$I_C = 100\text{ mA}$	600			V
$V_{CE(sat)}^*$	Collector-Emitter Saturation Voltage	$I_C = 5\text{ A}$ $I_B = 1.25\text{ A}$			1.5	V
$V_{BE(sat)}^*$	Base-Emitter Saturation Voltage	$I_C = 5\text{ A}$ $I_B = 1.25\text{ A}$			1.2	V
h_{FE}^*	DC Current Gain	$I_C = 6\text{ A}$ $V_{CE} = 1\text{ V}$ $I_C = 6\text{ A}$ $V_{CE} = 5\text{ V}$	5	4.5	9	
t_s t_f	INDUCTIVE LOAD Storage Time Fall Time	$I_C = 5\text{ A}$ $V_{BB(off)} = -2.5\text{ V}$ $I_{B(on)}(END) = 850\text{ mA}$ $f_h = 64\text{ KHz}$ $L_{BB(off)} = 2\text{ }\mu\text{H}$ (See Figure 1)		2.6 0.2	3 0.4	μs μs

* Pulsed: Pulse duration = 300 μs , duty cycle = 1.5 %.

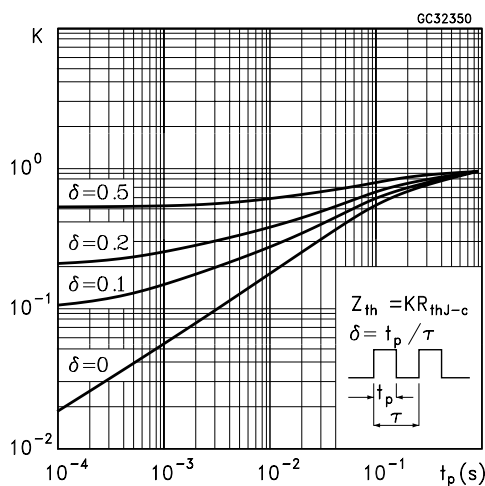
Safe Operating Area



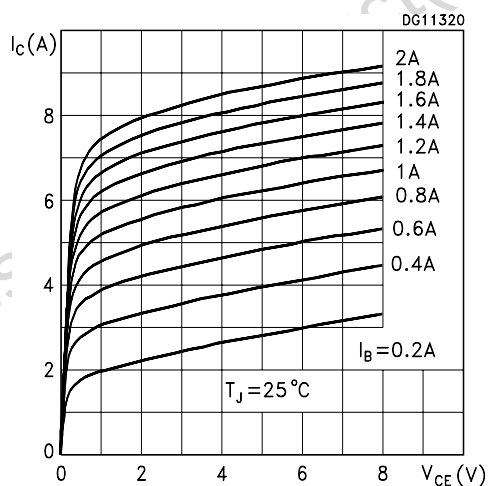
Derating Curve



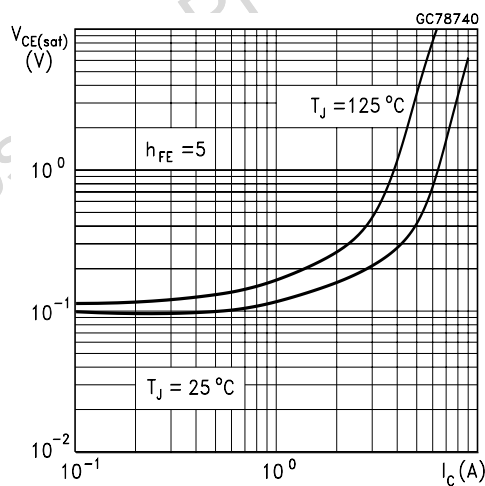
Thermal Impedance



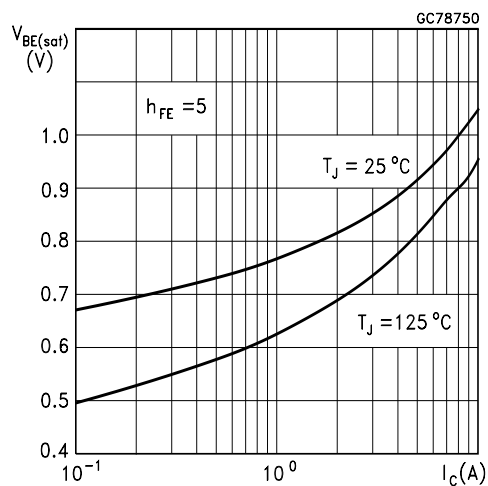
Output Characteristics



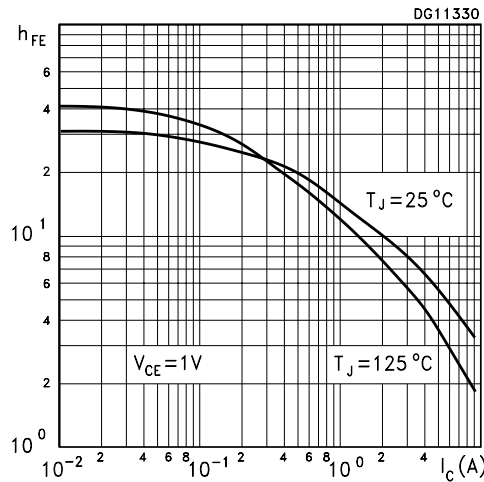
Collector-Emitter Saturation Voltage



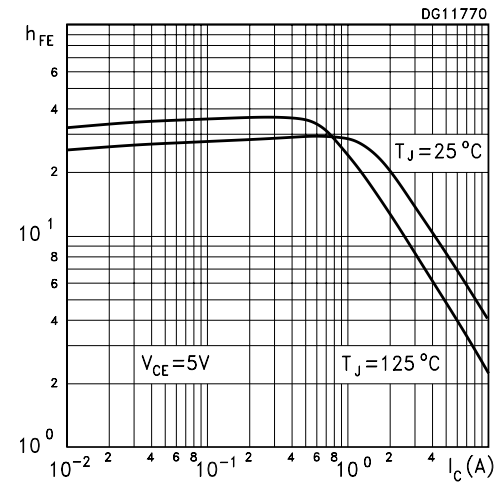
Base-Emitter Saturation Voltage



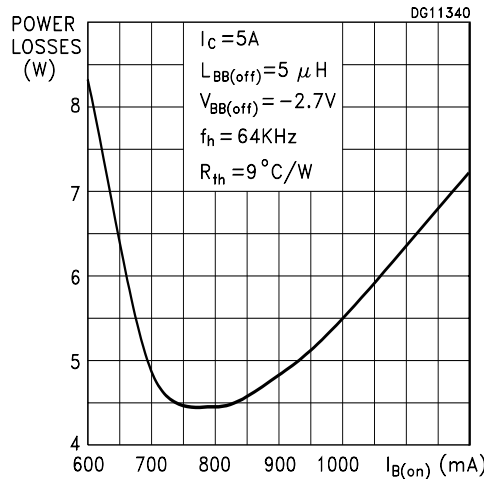
DC Current Gain



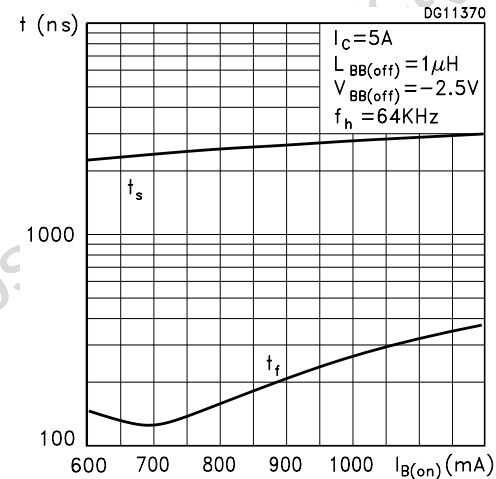
DC Current Gain



Power Losses



Inductive Load Switchin Times



Reverse Biased Safe Operating Area

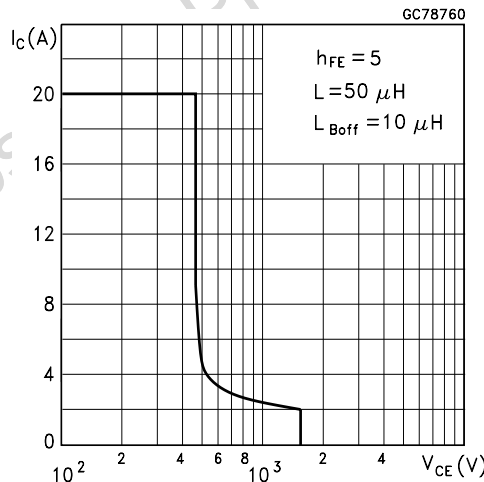
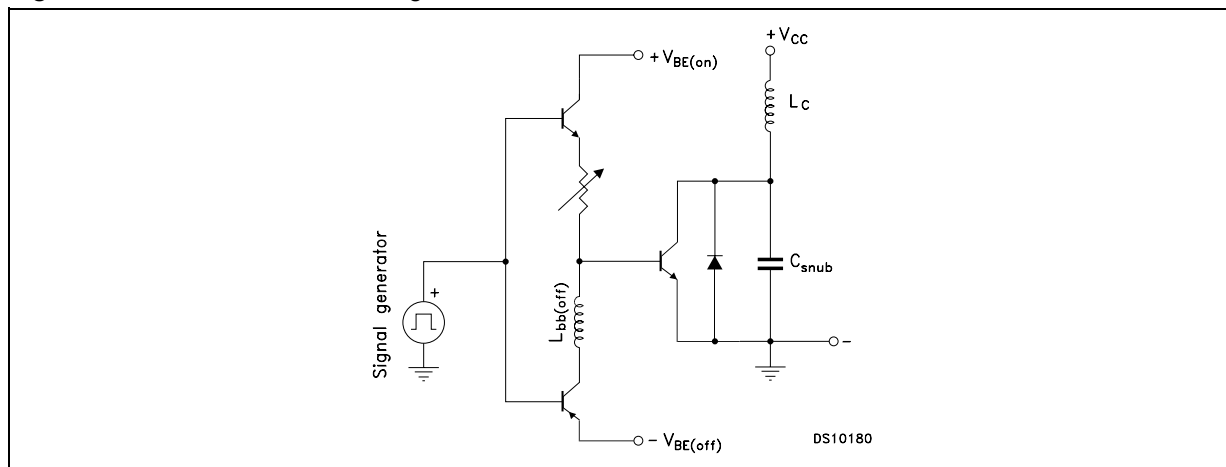
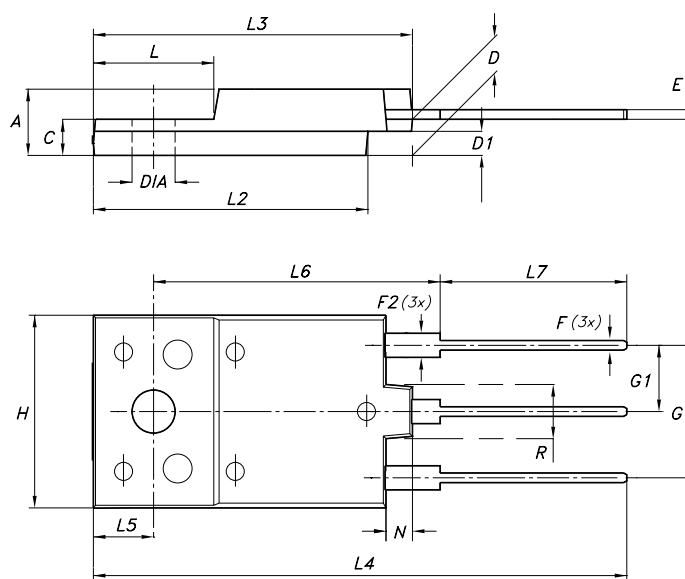


Figure 1: Inductive Load Switching Test Circuit

ISOWATT218FX MECHANICAL DATA

DIM.	mm.			inch		
	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.
A	5.30		5.70	0.209		0.224
C	2.80		3.20	0.110		0.126
D	3.10		3.50	0.122		0.138
D1	1.80		2.20	0.071		0.087
E	0.80		1.10	0.031		0.043
F	0.65		0.95	0.026		0.037
F2	1.80		2.20	0.071		0.087
G	10.30		11.50	0.406		0.453
G1		5.45			0.215	
H	15.30		15.70	0.602		0.618
L	9.80		10.20	0.386		0.402
L2	22.80		23.20	0.898		0.913
L3	26.30		26.70	1.035		1.051
L4	43.20		44.40	1.701		1.748
L5	4.30		4.70	0.169		0.185
L6	24.30		24.70	0.957		0.972
L7	14.60		15.00	0.575		0.591
N	1.80		2.20	0.071		0.087
R	3.80		4.20	0.150		0.165
DIA	3.40		3.80	0.134		0.150



- Weight : 5.6 g (typ.)
- Maximum Torque (applied to mounting flange) Recommended: 0.55 Nm; Maximum: 1 Nm
- The side of the dissipator must be flat within 80 mm

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